

isc N-Channel MOSFET Transistor

2SK3845

FEATURES

- Drain Current : ID= 70A@ TC=25 $^{\circ}\mathrm{C}$
- Drain Source Voltage
 - : V_{DSS}= 60V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 5.8 \text{m} \Omega \text{ (Max) @V_{GS}=10V}$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



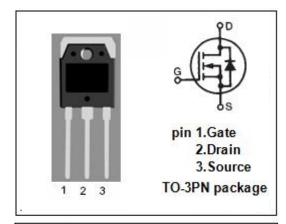
 motor drive, DC-DC converter, power switch and solenoid drive.

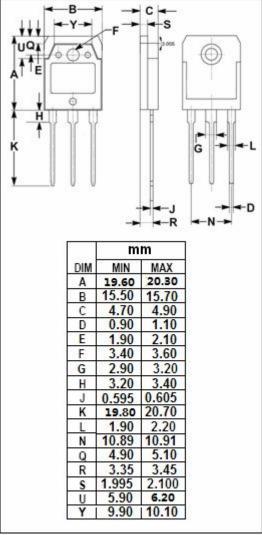
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	60	V
V _{GS}	Gate-Source Voltage-Continuous ±20		V
I _D	Drain Current-Continuous 70		А
І _{ОМ}	Drain Current-Single Pluse 280		А
P_D	Total Dissipation @T _C =25℃ 125		W
TJ	Max. Operating Junction Temperature -55~150		$^{\circ}$
T _{stg}	Storage Temperature -55~150		$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.0	°C/W





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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 10mA	60		V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 60V; V _{GS} = 0		100	uA
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±16V;V _{DS} = 0		±10	uA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 10V; I _D = 1mA	2.0	4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 35A		5.8	m Ω
V _{SD}	Forward On-Voltage	I _S = 70A; V _{GS} = 0		1.5	V



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